# imall

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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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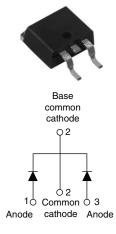
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Vishay High Power Products

#### HEXFRED<sup>®</sup> Ultrafast Soft Recovery Diode, 2 x 4 A



D<sup>2</sup>PAK

PRODUCT SUMMARY				
V <sub>R</sub>	600 V			
V <sub>F</sub> at 4 A at 25 °C	1.8 V			
I <sub>F(AV)</sub>	2 x 4 A			
t <sub>rr</sub> (typical)	17 ns			
T <sub>J</sub> (maximum)	150 °C			
Q <sub>rr</sub>	40 nC			
dl <sub>(rec)M</sub> /dt	280 A/µs			

#### FEATURES

- Ultrafast recovery
- Ultrasoft recovery
- Very low I<sub>RRM</sub>
- Very low Q<sub>rr</sub>
- Specified at operating conditions
- · Designed and qualified for industrial level

#### BENEFITS

- · Reduced RFI and EMI
- · Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

#### DESCRIPTION

HFA08TA60CS is a state of the art center tap ultrafast recovery diode. Employing the latest in epitaxial construction and advanced processing techniques it features a superb combination of characteristics which result in performance which is unsurpassed by any rectifier previously available. With basic ratings of 600 V and 4 A per leg continuous current, the HFA08TA60CS is especially well suited for use as the companion diode for IGBTs and MOSFETs. In addition to ultrafast recovery time, the HEXFRED® product line features extremely low values of peak recovery current (I<sub>BBM</sub>) and does not exhibit any tendency to "snap-off" during the t<sub>b</sub> portion of recovery. The HEXFRED features combine to offer designers a rectifier with lower noise and significantly lower switching losses in both the diode and the switching transistor. These HEXFRED advantages can help to significantly reduce snubbing, component count and heatsink sizes. The HEXFRED HFA08TA60CS is ideally suited for applications in power supplies and power conversion systems (such as inverters), motor drives, and many other similar applications where high speed, high efficiency is needed.

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	V <sub>R</sub>		600	V
Maximum continuous forward current	- IF	T <sub>C</sub> = 100 °C	4	
per device			8	А
Single pulse forward current	I <sub>FSM</sub>		25	A
Maximum repetitive forward current	I <sub>FRM</sub>		16	
Maximum power dissipation	P <sub>D</sub>	T <sub>C</sub> = 25 °C	25	W
		T <sub>C</sub> = 100 °C	10	vv
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		- 55 to + 150	°C

## HFA08TA60CS



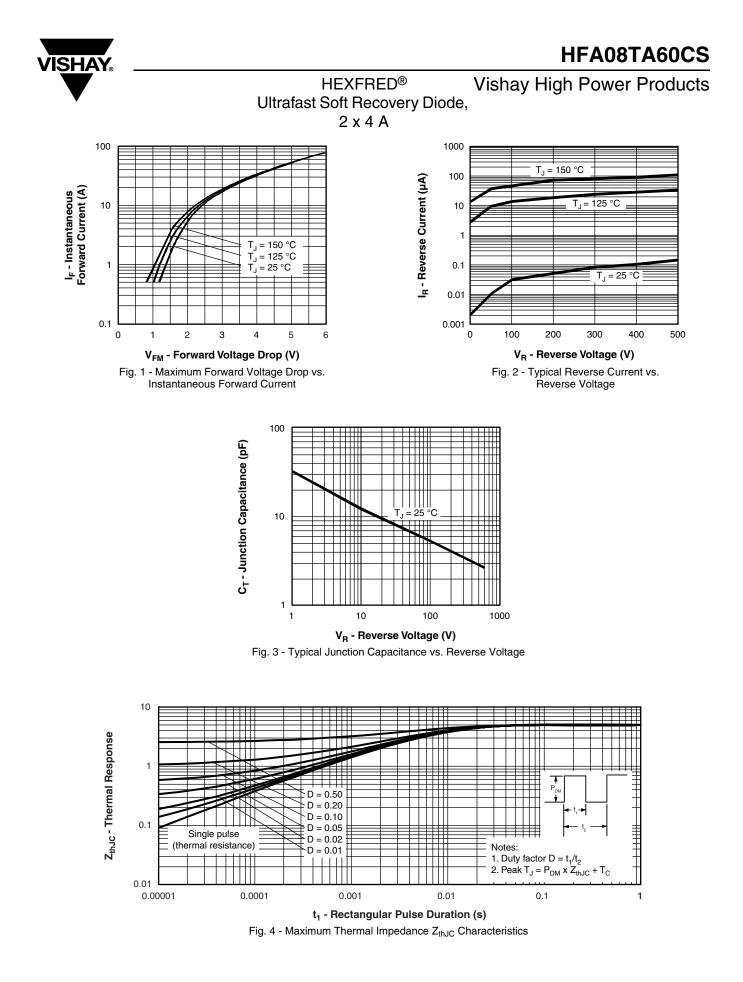
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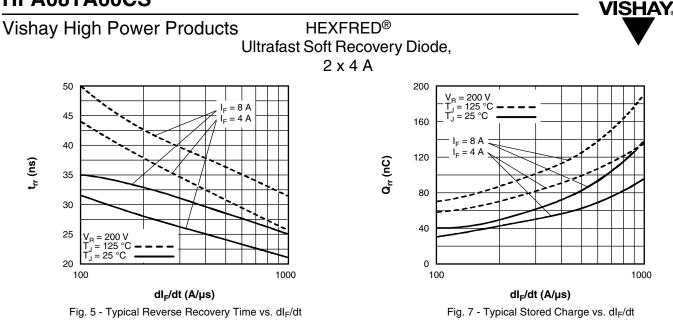
<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V <sub>BR</sub>	I <sub>R</sub> = 100 μA		600	-	-	
Maximum forward voltage V <sub>FM</sub>		I <sub>F</sub> = 4.0 A		-	1.5	1.8	v
	I <sub>F</sub> = 8.0 A	See fig. 1	-	1.8	2.2	]	
		I <sub>F</sub> = 4.0 A, T <sub>J</sub> = 125 °C		-	1.4	1.7	
Maximum reverse		$V_{\rm R} = V_{\rm R}$ rated		-	0.17	3.0	
leakage current	I <sub>RM</sub>	$T_J = 125 \text{ °C}, V_R = 0.8 \text{ x } V_R \text{ rated}$ See fig.	$I_{RM}$ T <sub>J</sub> = 125 °C, V <sub>R</sub> = 0.8 x V <sub>R</sub> rated See fig. 2	-	44	300	μΑ
Junction capacitance	CT	V <sub>R</sub> = 200 V	See fig. 3	-	4.0	8.0	pF
Series inductance	L <sub>S</sub>	Measured lead to lead 5 mm from package body - 8.0 -		nH			

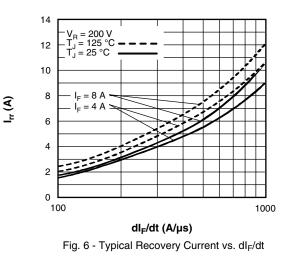
<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
<b>.</b>	t <sub>rr</sub>	$I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t = 200 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$		-	17	-	
Reverse recovery time See fig. 5, 6 and 16	t <sub>rr1</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 4.0 A dI <sub>F</sub> /dt = 200 A/μs V <sub>R</sub> = 200 V	-	28	42	ns
	t <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	38	57	
Peak recovery current	I <sub>RRM1</sub>	T <sub>J</sub> = 25 °C		-	2.9	5.2	A
See fig. 7 and 8	I <sub>RRM2</sub>	T <sub>J</sub> = 125 °C		-	3.7	6.7	
Reverse recovery charge	Q <sub>rr1</sub>	T <sub>J</sub> = 25 °C		-	40	60	
See fig. 9 and 10	Q <sub>rr2</sub>	T <sub>J</sub> = 125 °C		-	70	105	nC
Peak rate of fall of recovery current during t <sub>h</sub>	dl <sub>(rec)M</sub> /dt1	T <sub>J</sub> = 25 °C		-	280	-	- A/μs
	T <sub>J</sub> = 125 °C		-	235	-	πμο	

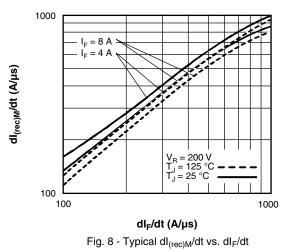
THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	MBOL TEST CONDITIONS		TYP.	MAX.	UNITS
Lead temperature	T <sub>lead</sub>	0.063" from case (1.6 mm) for 10 s	-	-	300	°C
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	5.0	K/W
Thermal resistance, junction to ambient	R <sub>thJA</sub>	Typical socket mount	-	-	80	- r∖/vv
Waight			-	2.0	-	g
Weight			-	0.07	-	oz.
Mounting torque			6.0 (5.0)	-	12 (10)	kgf ⋅ cm (lbf ⋅ in)
Marking device		Case style D <sup>2</sup> PAK		HFA08	FA60CS	



## HFA08TA60CS









#### HFA08TA60CS

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2 x 4 A

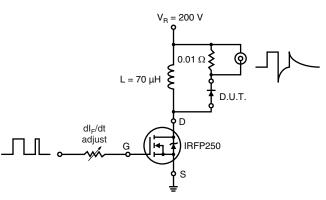


Fig. 9 - Reverse Recovery Parameter Test Circuit

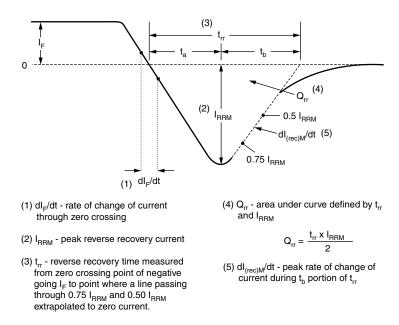


Fig. 10 - Reverse Recovery Waveform and Definitions

LINKS TO RELATED DOCUMENTS				
Dimensions http://www.vishay.com/doc?95046				
Part marking information http://www.vishay.com/doc?95054				
Packaging information	http://www.vishay.com/doc?95032			



Vishay

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